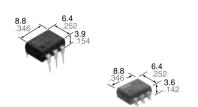






### **Greatly increase load current** (2.5A). Load voltage is 60V.

# HE PhotoMOS (AQV252G)



#### **FEATURES**

- 1. Greatly increased load current in the same package size.
- 2. Greatly improved specs allow you to use this in place of mercury and mechanical relays.

#### TYPICAL APPLICATIONS

- Crime and fire prevention market (use in I/O for alarm and security devices, etc.)
- · Measuring instrument market (circuit testers, etc.)

#### mm inch



#### **TYPES**

Туре	Output rating*			Par	Packing quantity			
			Through hole terminal	Surface-mount terminal				
	Load voltage	Load current			Tape and reel packing style		Tube	Tape and reel
			Tube packing style		Picked from the 1/2/3-pin side	Picked from the 4/5/6-pin side		
AC/DC type	60 V	2.5 A	AQV252G	AQV252GA	AQV252GAX	AQV252GAZ	1 tube contains 50 pcs. 1 batch contains 500 pcs.	1,000 pcs.

<sup>\*</sup>Indicate the peak AC and DC values.

Note: For space reasons, the SMD terminal shape indicator "A" and the package type indicator "X" and "Z" are omitted from the seal.

#### **RATING**

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

	Item	Symbol	Type of connection	AQV252G(A)	Remarks	
	LED forward current	lF		50 mA		
loout	LED reverse voltage	VR		5 V		
Input	Peak forward current	IFP		1 A	f = 100 Hz, Duty factor = 0.1%	
	Power dissipation	Pin	1	75 mW		
	Load voltage (peak AC)	VL		60 V		
		l.	Α	2.5 A		
Outrast	Continuous load current (peak AC)		В	3.5 A	A connection: Peak AC, DC B. C connection: DC	
Output	(peak AO)		С	5.0 A	- B, O connection. BO	
	Peak load current	Ipeak		6.0 A	100ms (1 shot), V <sub>L</sub> = DC	
	Power dissipation	Pout		500 mW		
Total power dissipation		P⊤		550 mW		
I/O isolation voltage		Viso		1,500 V AC		
Temperature limits	Operating	Topr		<b>−40°C</b> to <b>+85°C</b> −40°F to +185°F	Non-condensing at low temperatures	
	Storage	T <sub>stg</sub>		-40°C to +100°C -40°F to +212°F		

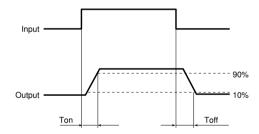
## HE PhotoMOS (AQV252G)

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

		Symbol	Type of connection	AQV252G(A)	Condition		
Input	LED operate	Typical	Fon	_	0.5 mA	- IL = 100mA	
	current	Maximum	IFON		3 mA		
	LED turn off	Minimum	Foff	_	0.2 mA	l <sub>L</sub> = 100mA	
	current	Typical			0.45 mA	IL = TOUTIA	
	LED dropout voltage	Typical	VF		1.32 V (1.14 V at I <sub>F</sub> = 5 mA)	I <sub>F</sub> = 50 mA	
		Maximum			1.5 V	7 IF = 30 IIIA	
Output	On resistance	Typical	Ron	Α	0.08 Ω		
		Maximum			0.12 Ω		
		Typical	Ron	В	0.04 Ω	│ IF = 5 mA │ IL = Max.	
		Maximum			0.06 Ω	Within 1 s on time	
Cuipui		Typical	Ron	С	0.02 Ω		
		Maximum			0.03 Ω		
	Off state leakage current	Maximum	Leak	_	1 μΑ	IF = 0 mA VL = Max.	
Transfer characteristics		Typical	Ton	_	1.1 ms	I <sub>F</sub> = 5 mA	
	Turn on time*	Maximum			5.0 ms	I <sub>L</sub> = 100 mA V <sub>L</sub> = 10 V	
	Turn off time*	Typical	- T <sub>off</sub>	_	0.25 ms	I <sub>F</sub> = 5 mA I <sub>L</sub> = 100 mA	
	lum on time	Maximum			0.5 ms	V <sub>L</sub> = 10 V	
	I/O conscitones	Typical	Ciso	_	0.8 pF	f = 1 MHz	
	I/O capacitance	Maximum			1.5 pF	V <sub>B</sub> = 0 V	
	Initial I/O isolation resistance	Minimum	Riso	_	1,000 ΜΩ	500 V DC	

Note: Recommendable LED forward current I<sub>F</sub> = 5 to 10 mA.

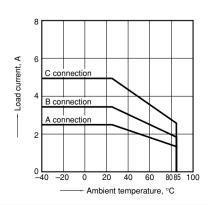
\*Turn on/Turn off time



### REFERENCE DATA

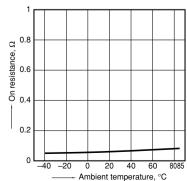
1. Load current vs. ambient temperature characteristics

Allowable ambient temperature:  $-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$   $-40^{\circ}\text{F}$  to  $+185^{\circ}\text{F}$ 



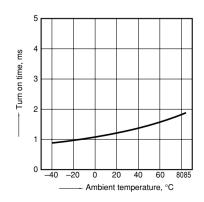
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6; LED current: 5 mA; Load voltage: Max. (DC) Continuous load current: Max.(DC)



3. Turn on time vs. ambient temperature characteristics

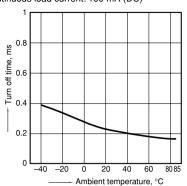
LED current: 5 mA; Load voltage: 10 V (DC); Continuous load current: 100 mA (DC)



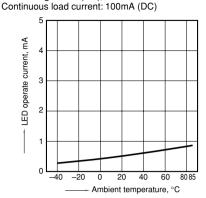
### HE PhotoMOS (AQV252G)

4. Turn off time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: 10 V (DC); Continuous load current: 100 mA (DC)

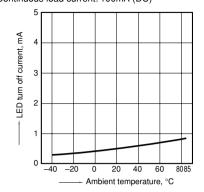


5. LED operate current vs. ambient temperature characteristics Load voltage: 10 V (DC);

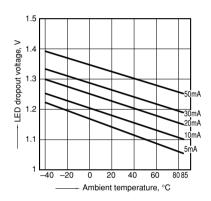


6. LED turn off current vs. ambient temperature characteristics

Load voltage: 10 V (DC); Continuous load current: 100mA (DC)

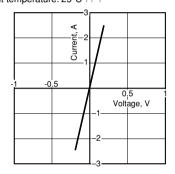


7. LED dropout voltage vs. ambient temperature characteristics LED current: 5 to 50 mA



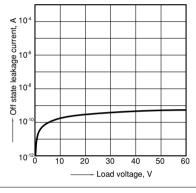
8. Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 4 and 6; Ambient temperature: 25°C 77°F



9. Off state leakage current vs. load voltage characteristics

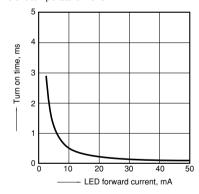
Measured portion: between terminals 4 and 6; Ambient temperature: 25°C  $77^{\circ}F$ 



10. Turn on time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6; Load voltage: 10 V (DC);

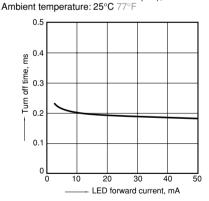
Continuous load current: 100 mA (DC); Ambient temperature: 25°C 77°F



11. Turn off time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6; Load voltage: 10 V (DC);

Continuous load current: 100 mA (DC);



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 4 and 6;

Frequency: 1 MHz;

Ambient temperature: 25°C 77°F

